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A7632/T49100

Under the Paperwork Reduction Act of EAT & TRADE Complete if Known Substitute for form 1449A/PTO Application Number 10/627,228 INFORMATION DISCLOSURE July 25, 2003 Filing Date Moghadam et. al. STATEMENT BY APPLICANT First Named Inventor Unassigned -Art Unit Unassigned ---Examiner Name (use as many sheets as necessary)

Attorney Docket Number

U.S. PATENT DOCUMENTS Pages, Columns, Lines, Where Relevant Passages or Relevant Document Number Name of Patentee or Publication Date MM-DD-YYYY Applicant of Cited Document Cite Number Kind Code<sup>2</sup> (if known) Examiner res Appear Bayman et al. 07-22-2003 US-6,596,654 B1 AA SHV

				FOREIGN PA	TENT DOCUME	NTS	Column Lines	
	Cita	Foreign Patent Document		Publication Date	Name of Patentee or	Pages, Columns, Lines, Where Relevant		
Examiner Initials*	Cite No. <sup>1</sup>	Country Code <sup>3</sup>	Number <sup>4</sup>	Kind Code <sup>s</sup> (if known)_	MM-DD-YYYY	Applicant of Cited Document	Passages or Relevant Figures Appear	T°
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Substitute for form 1449/PTO Complete if Known **Application Number Unassigned** INFORMATION DISCLOSURE Filing Date Filed Herewith STATEMENT BY APPLICANT First Named Inventor Moghadam, Farhad K., et. al. Art Unit Unassigned. (use as many sheets as necessary) **Examiner Name** <del>Unassigned</del> A7632/T49100 Attorney Docket Number Page

		NON PATENT LITERATURE DOCUMENTS	
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SHV	AS	"Atomic Layer Deposition" by Physical Inorganic Chemistry, Institute of Applied Synthetic Chemistry, downloaded from website http://www.ias.tuwien.ac.at/research/fghh/research/pic_research_ald.html on 7/23/02	
SHV	AT	GEORGE et al., "Atomic layer controlled deposition of SiO <sub>2</sub> and Al <sub>2</sub> O <sub>3</sub> using ABAB binary reaction sequence chemistry," <u>Applied Surface Science</u> , 82/83:460-467 (1994).	
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